

# Week 15

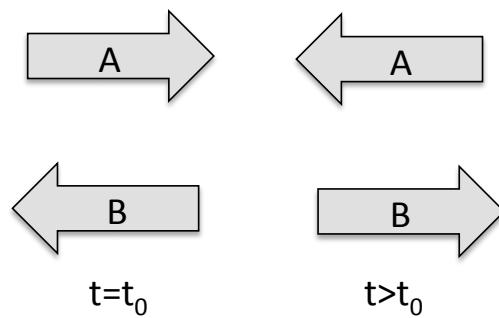
Review of Semesters 1 and 2

# Organic & Inorganic Semiconductors: What makes them different?

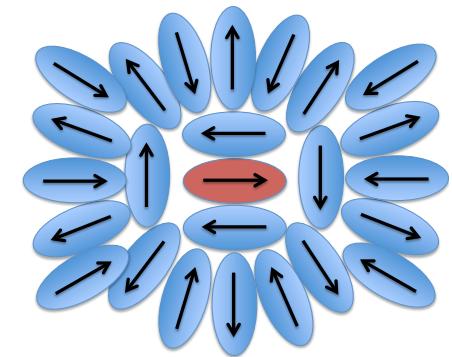
Property	Organics	Inorganics
Bonding	van der Waals	Covalent/Ionic
Charge Transport	Polaron Hopping	Band Transport
Mobility	$\sim 1 \text{ cm}^2/\text{V}\cdot\text{s}$	$\sim 1000 \text{ cm}^2/\text{V}\cdot\text{s}$
Absorption	$10^5\text{-}10^6 \text{ cm}^{-1}$	$10^4\text{-}10^5 \text{ cm}^{-1}$
Excitons	Frenkel	Wannier-Mott
Binding Energy	$\sim 500\text{-}800 \text{ meV}$	$\sim 10\text{-}100 \text{ meV}$
Exciton Radius	$\sim 10 \text{ \AA}$	$\sim 100 \text{ \AA}$

# van der Waals bonding

- Purely electrostatic *instantaneous* induced dipole-induced dipole interaction between  $\pi$ -systems of nearby molecules.



Medium around the dipole is *polarized*



$$U(r_{12}) = -\frac{A_{disp}}{r_{12}^6} \quad : \text{Dispersion interaction}$$

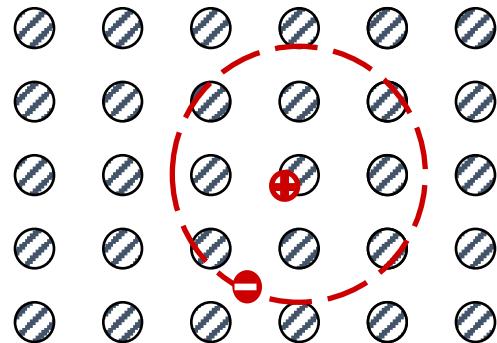
$$U(r) = 4\epsilon \left[ \left( \frac{\sigma}{r} \right)^{12} - \left( \frac{\sigma}{r} \right)^6 \right] \quad : \text{Lennard-Jones 6-12 potential (includes core repulsion)}$$

# Organic Semiconductors are Excitonic Materials

Inorganics → Organics

## Wannier exciton

Inorganic semiconductors



## SEMICONDUCTOR PICTURE

CONDUCTION BAND



VALENCE BAND



GROUND STATE    WANNIER EXCITON

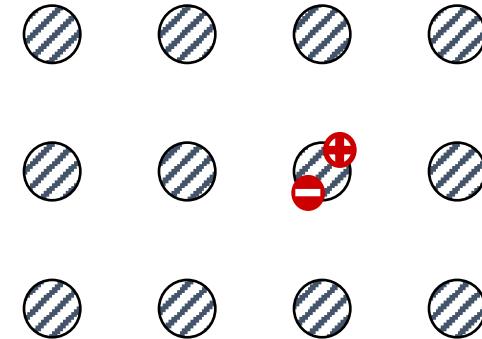
Dielectric constant ~15

binding energy ~10meV (unstable at RT)  
radius ~100Å

Organics

## Frenkel exciton

Organic materials



Charge Transfer (CT) Exciton  
(bridge between W and F)



## MOLECULAR PICTURE

$S_1$

$S_0$

$S_1$

$S_0$

GROUND STATE

FRENKEL EXCITON

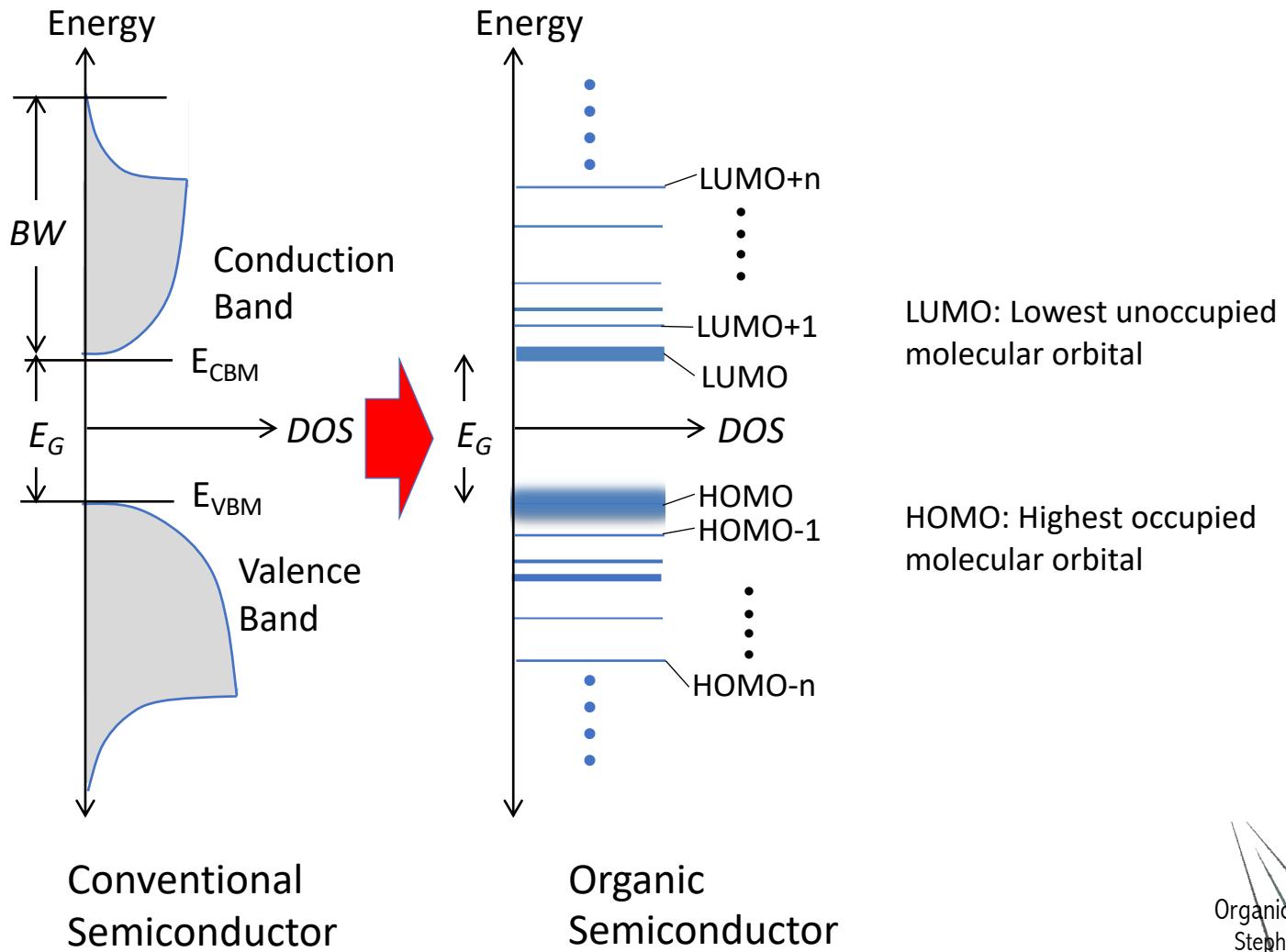
Štefan R. Černák

treat excitons  
as **chargeless particles**  
capable of diffusion.

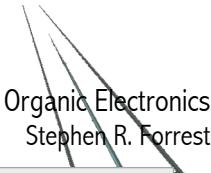
Transport of  
energy (not  
charge)

Dielectric constant ~2  
binding energy ~1eV (stable at RT)  
radius ~10Å

# *Band Structure* is Replaced by *Energy Levels*



It is essential to keep your terminology clear: **Band gaps** exist in inorganics, **energy gaps** without extended bands are the rule (but with important exceptions) in organics.<sup>5</sup>



# Singlet and triplet states

Spatially symm.      Spin antisymm.

$$\psi(\mathbf{r}_1, \mathbf{r}_2; 0, 0) = \frac{1}{\sqrt{2}} (\phi_a(\mathbf{r}_1)\phi_b(\mathbf{r}_2) + \phi_a(\mathbf{r}_2)\phi_b(\mathbf{r}_1)) (\alpha_1\beta_2 - \alpha_2\beta_1)$$

$S$      $m_S$

**Singlet**  
 $S=0$   
 $m_s=0$

$$\psi(\mathbf{r}_1, \mathbf{r}_2; 1, 1) = \frac{1}{\sqrt{2}} (\phi_a(\mathbf{r}_1)\phi_b(\mathbf{r}_2) - \phi_a(\mathbf{r}_2)\phi_b(\mathbf{r}_1)) \alpha_1\alpha_2$$

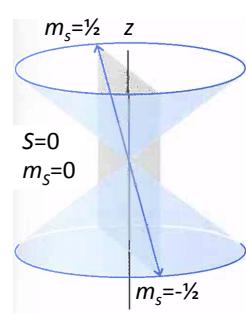
$$\psi(\mathbf{r}_1, \mathbf{r}_2; 1, 0) = \frac{1}{\sqrt{2}} (\phi_a(\mathbf{r}_1)\phi_b(\mathbf{r}_2) - \phi_a(\mathbf{r}_2)\phi_b(\mathbf{r}_1)) (\alpha_1\beta_2 + \alpha_2\beta_1)$$

**Triplet**  
 $S=1$   
 $m_s=\pm 1, 0$

and

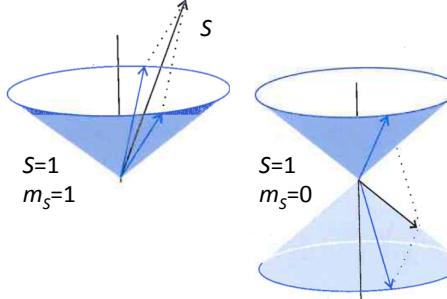
$$\psi(\mathbf{r}_1, \mathbf{r}_2; 1, -1) = \frac{1}{\sqrt{2}} (\phi_a(\mathbf{r}_1)\phi_b(\mathbf{r}_2) - \phi_a(\mathbf{r}_2)\phi_b(\mathbf{r}_1)) \beta_1\beta_2$$

180° out of phase

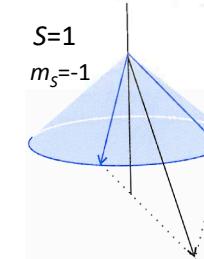


(a)

In phase

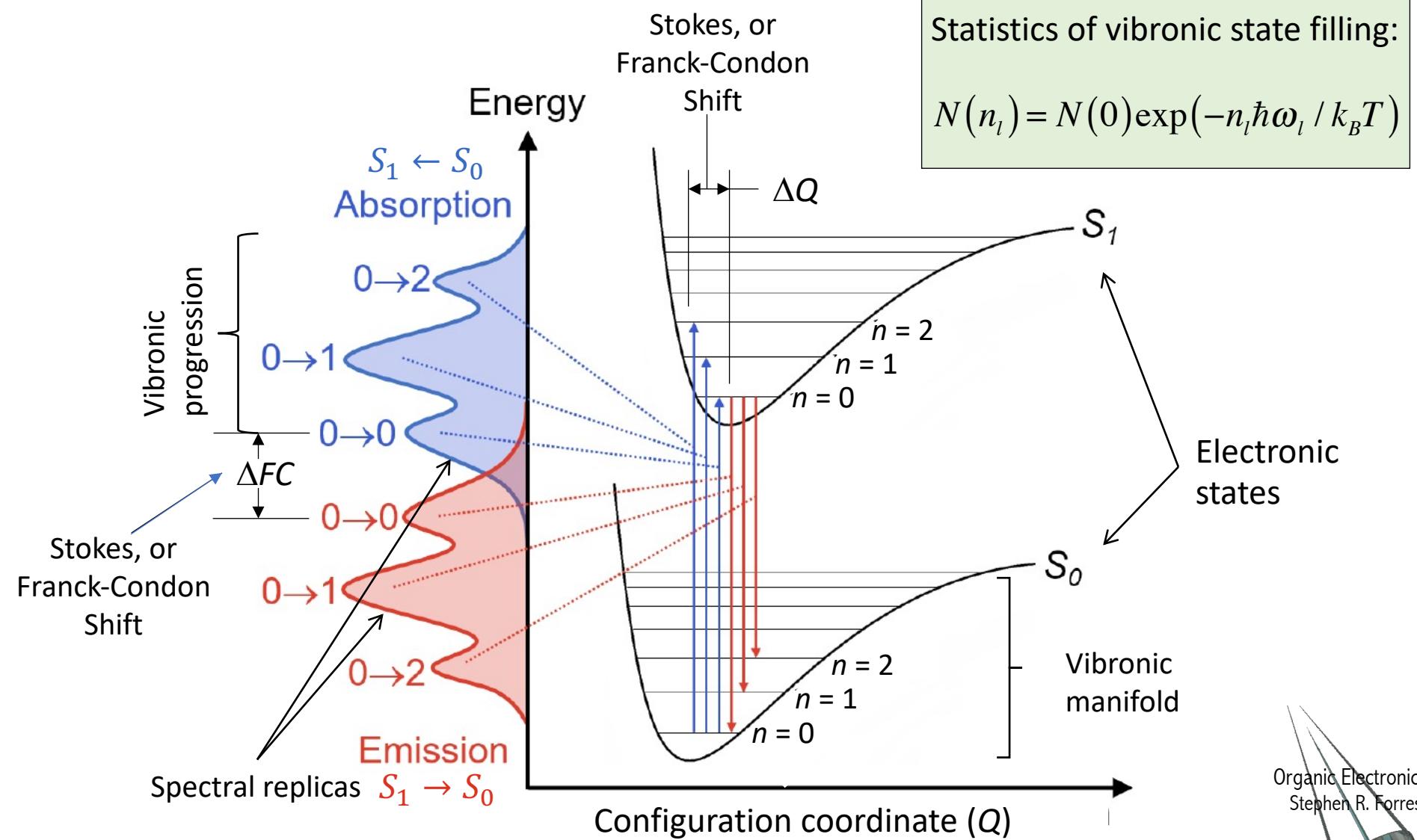


(b)



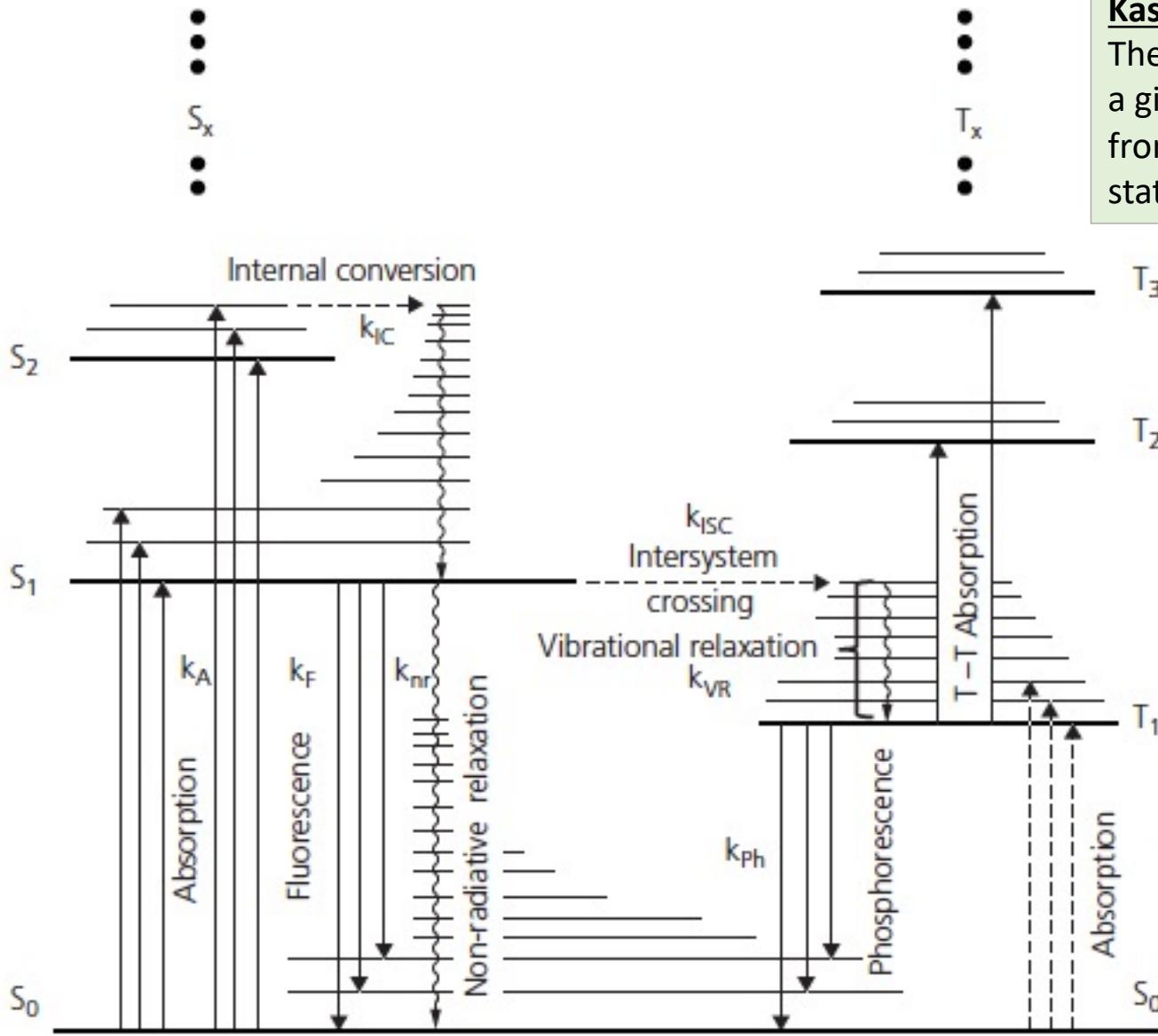
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# Understanding molecular spectra



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# Jablonski Diagrams: Life Histories of Excitons



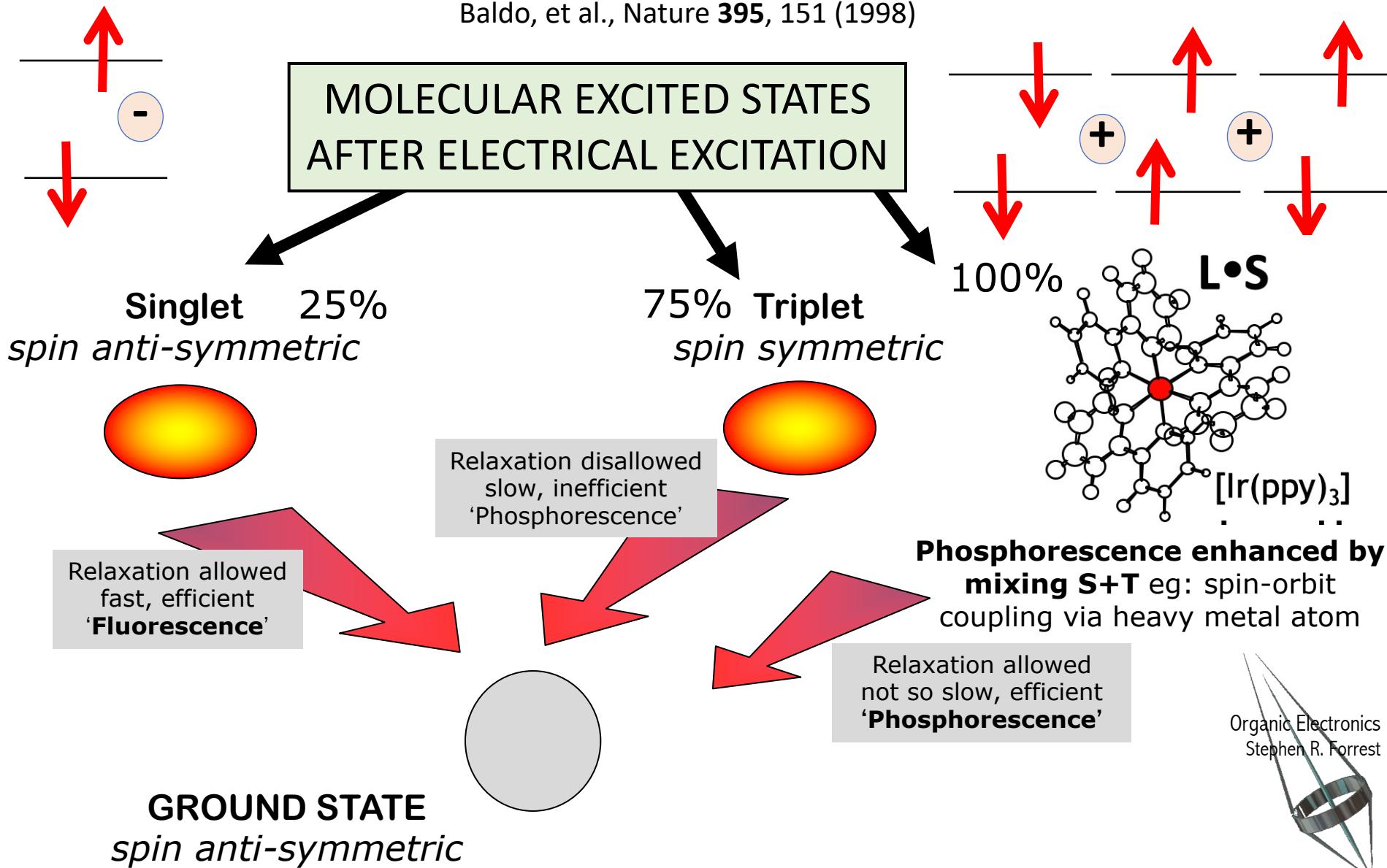
## Kasha's rule

The radiative transition from a given spin manifold occurs from the lowest excited state.

# 100% Internal Efficiency via Spin-Orbit Coupling

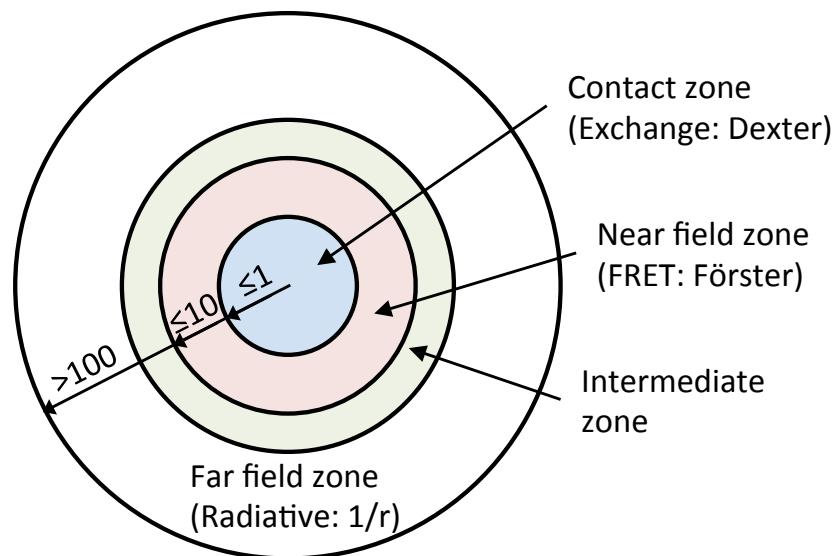
Heavy metal induced electrophosphorescence ~100% QE

Baldo, et al., Nature 395, 151 (1998)



# Energy Transfer

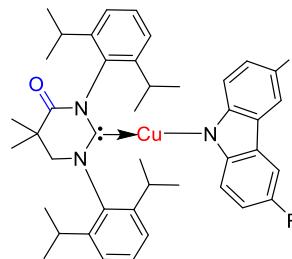
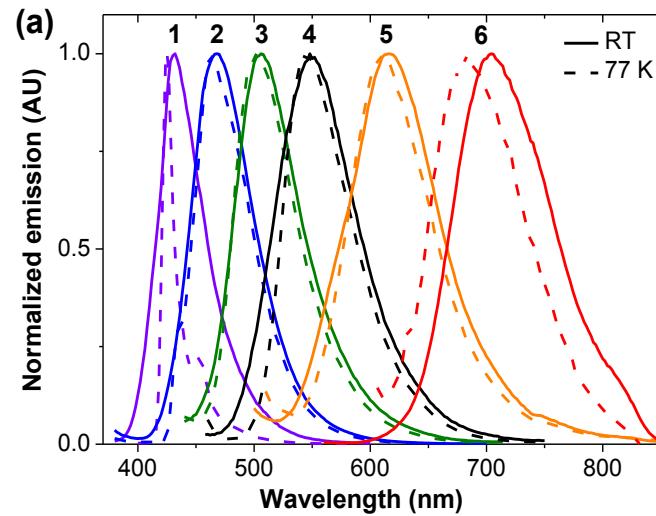
- If excitons are mobile in the solid, they must move from molecule to molecule
  - ✧ The microscopic “hopping” between neighboring molecules = energy transfer



Different transfer ranges accessed by different processes

# Energy Gap Law

- The larger the energy gap, the lower the probability for non-radiative recombination.  
 ⇒ As the energy gap of a molecular species decreases, radiative transitions have a higher probability for non-radiative decay.

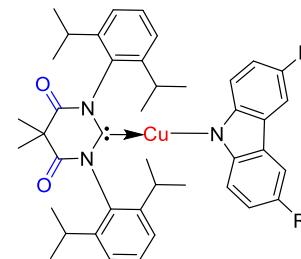


Carbene = MAC\*

R, R' = CN (1)

R = CN, R' = H (2)

R, R' = H (3)

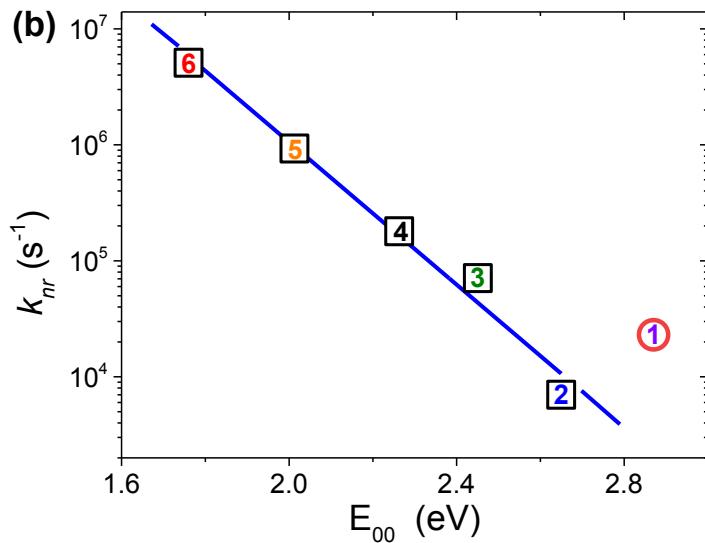


Carbene = DAC\*

R, R' = CN (4)

R = CN, R' = H (5)

R, R' = H (6)



$$k_{if} = A \exp\left(-\gamma E_g / \hbar \omega_p\right)$$

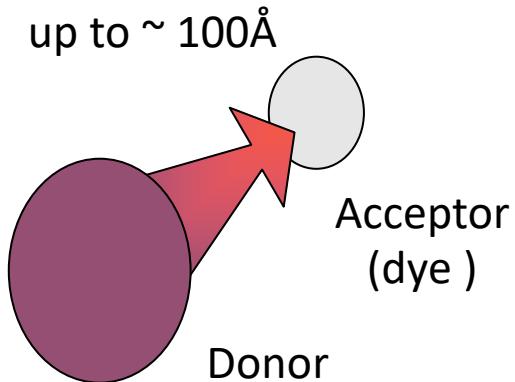
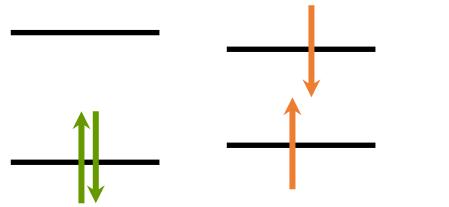
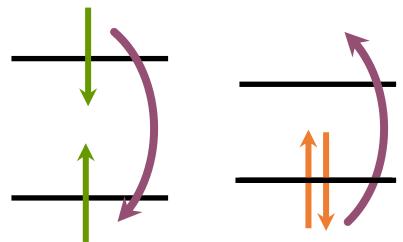
$$\gamma = \log\left(\frac{E_g}{\Omega E_p}\right) - 1$$

$\Omega$  = number of modes contributing to the maximum phonon energy,  
 $= \frac{1}{2}$  the Stokes shift.

# Energy Transfer from Host to Dopant: A Review

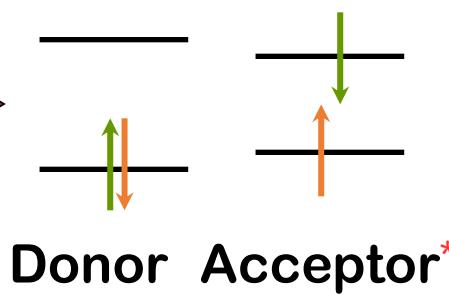
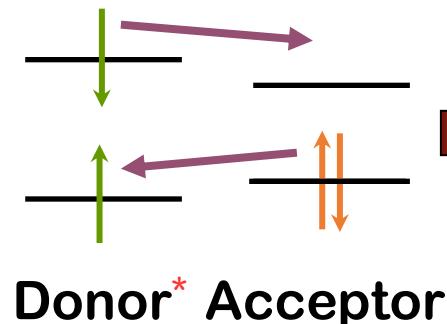
Förster:

- resonant dipole-dipole coupling
- donor and acceptor transitions must be allowed

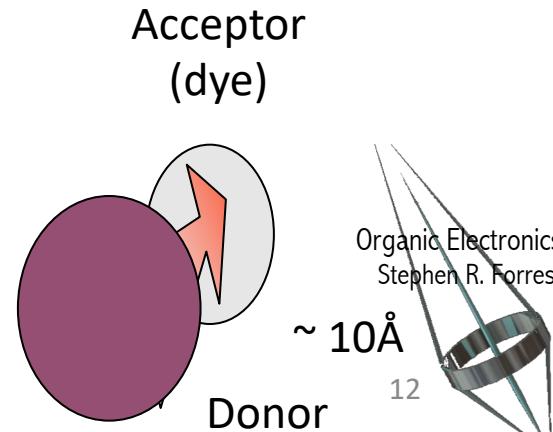


Electron Exchange (Dexter):

- diffusion of excitons from donor to acceptor by simultaneous charge exchange: short range

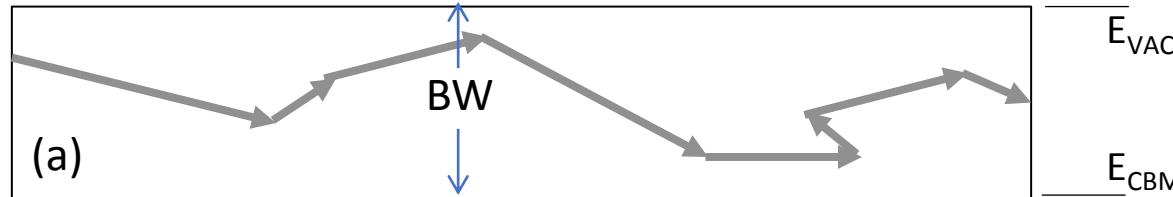


*spin is conserved: e.g. singlet-singlet or triplet-triplet*



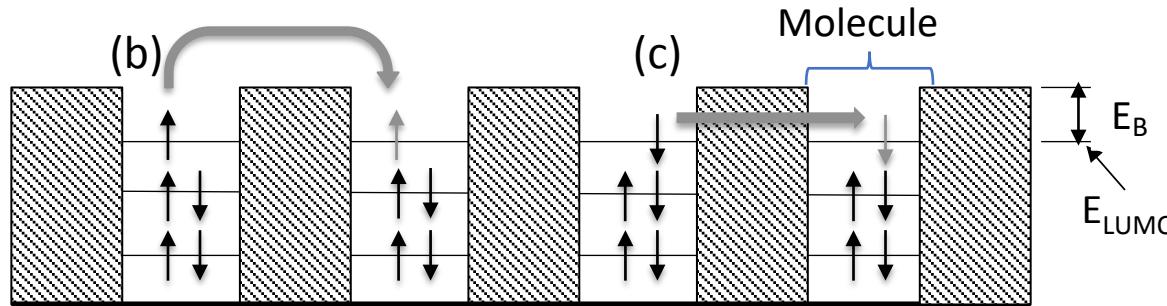
# Modes of Conduction

## Band transport



- Coherent
- Charge mean free path  $\lambda \gg a$
- $BW > k_B T, \hbar\omega_0$

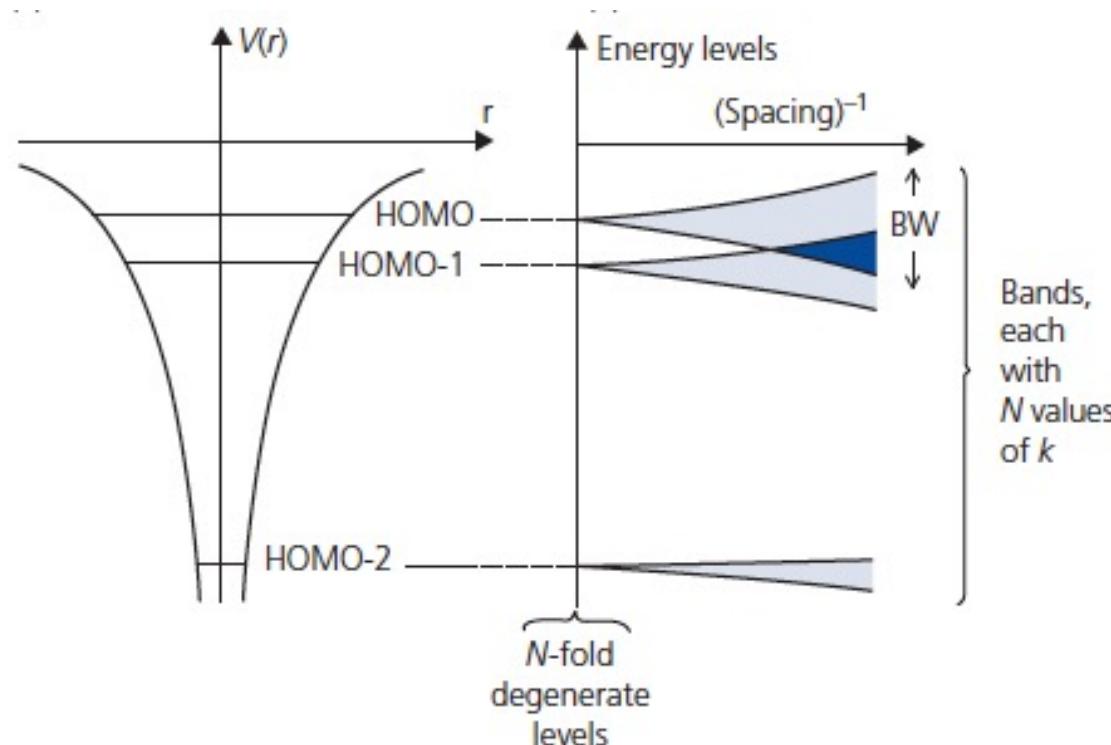
## Hopping and tunneling transport



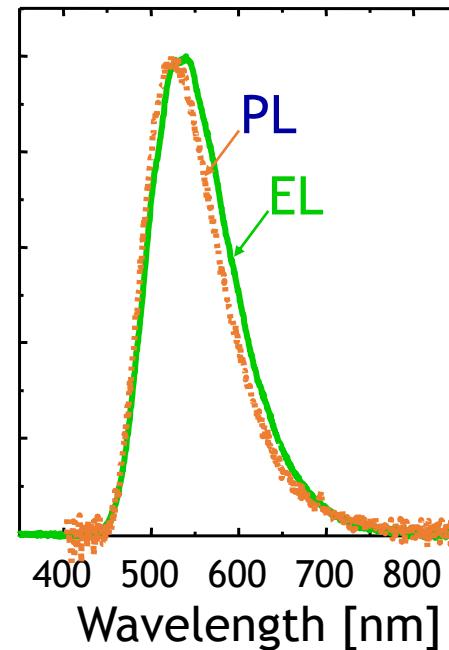
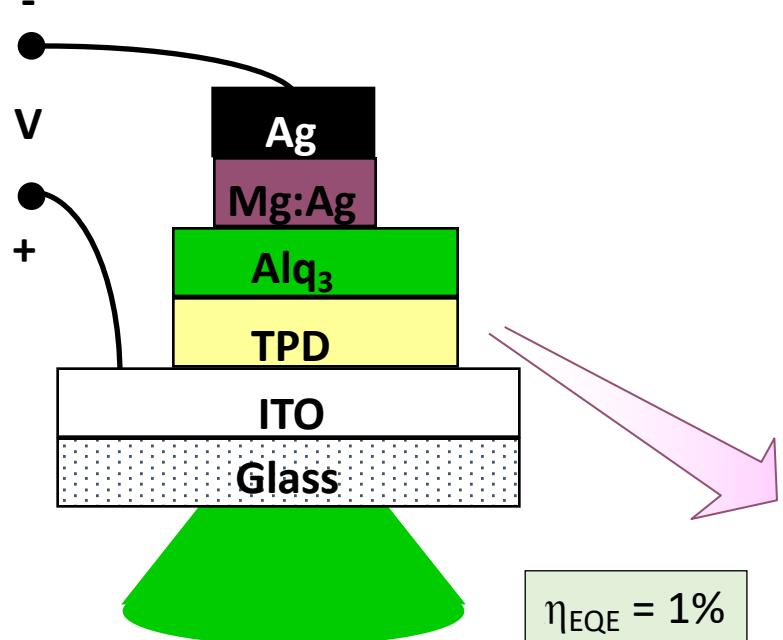
- Incoherent (each step independent of previous)
- Charge mean free path  $\lambda \sim a$
- Tunneling between states of equal energy is band-like
- $BW < k_B T, \hbar\omega_0$

# Transport Bands in Organics

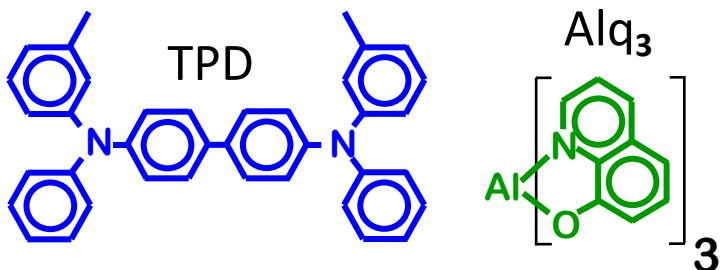
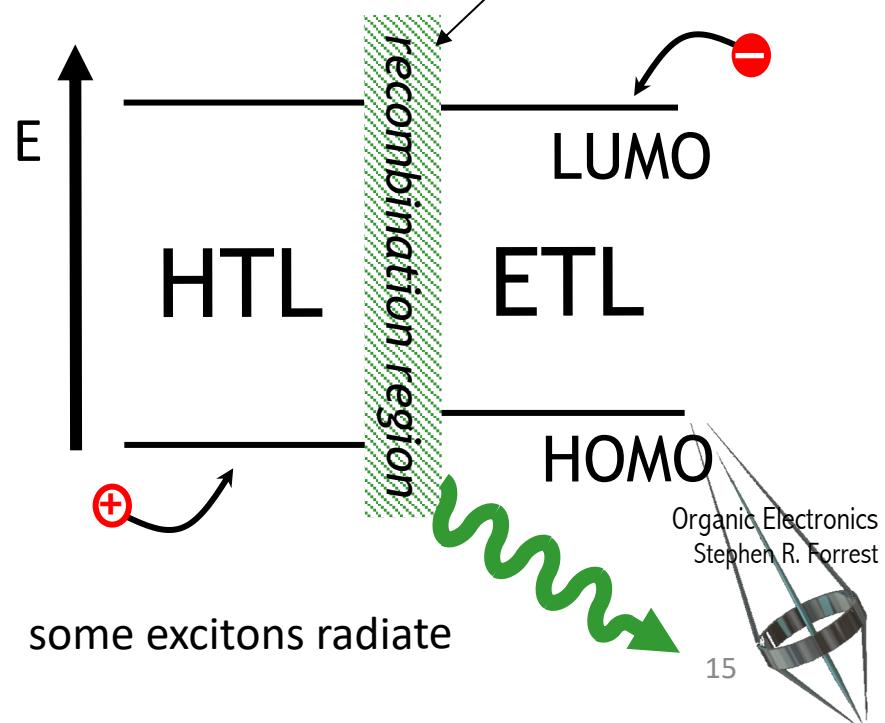
- **Tight binding** approximation is useful due to importance of only nearest neighbor interactions
- Recall case of dimers and larger aggregates on exciton spectrum. Close proximity of neighbors results in:
  - Coulomb repulsion
  - Pauli exclusion➤ Splitting leads to broadening of discrete energies into bands



# Organic Light Emitting Diode (OLED)

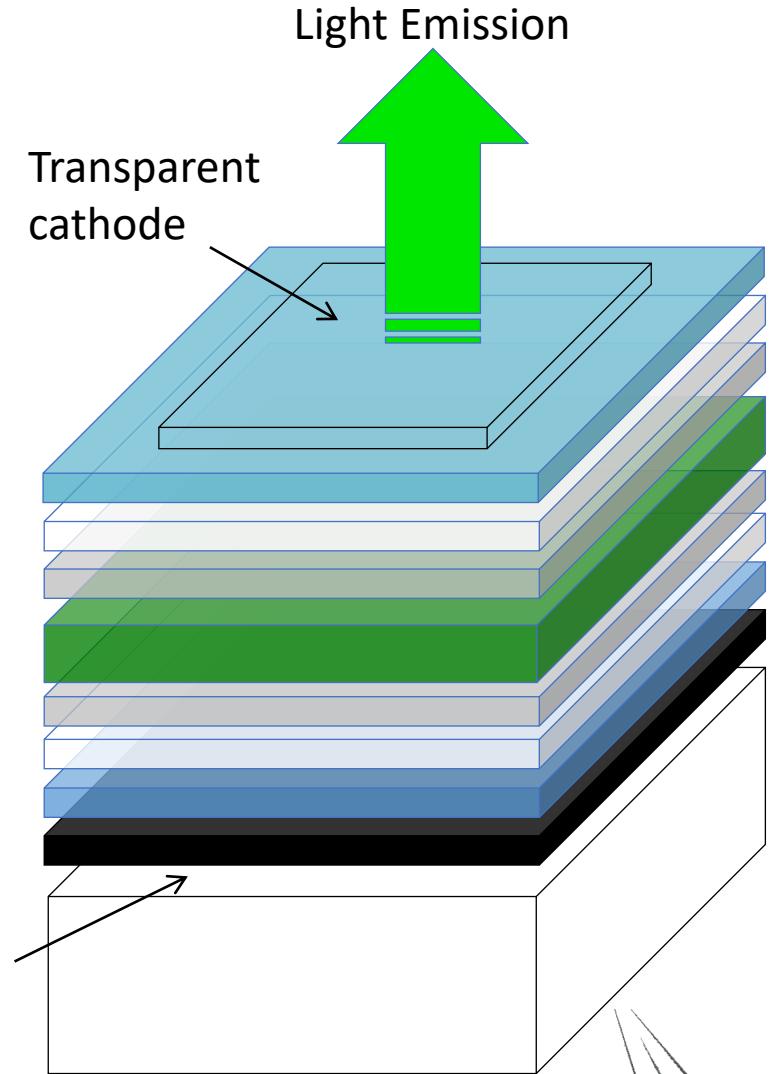
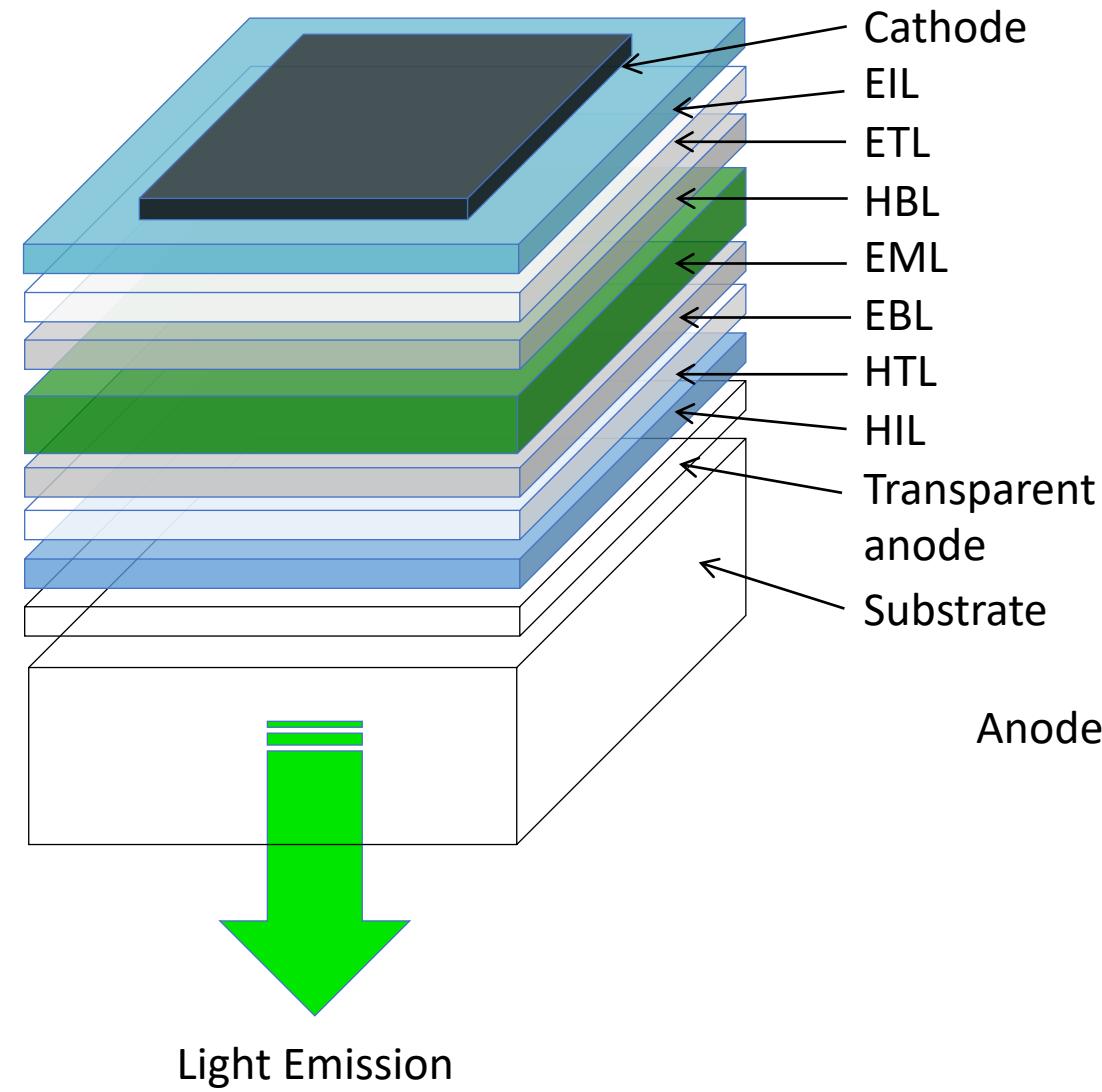


electrons and holes  
form excitons  
(bound e-h<sup>+</sup> pairs)



Tang & van Slyke, Appl. Phys. Lett., 51, 913 (1987)

# Today's OLEDs Are Not So Simple



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# OLED efficiency

$$\eta_{ext} = \eta_{int} \eta_{out} = \gamma \chi_r \phi_p \eta_{out}$$

$\sim 100\%$       ?       $\sim 100\%$        $\sim 20\%$

$\gamma$ : charge carrier balance factor  
ratio of e/h

$\chi_r$ : luminescent exciton production

$\phi_p$ : quantum efficiency of fluorescence

$\eta_{out}$ : light out-coupling efficiency

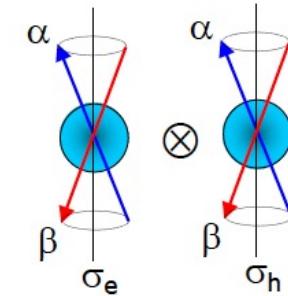
1. Fluorescence is restricted to singlet excitons  $\chi_r \sim 25\%$

Singlet

$$\frac{1}{\sqrt{2}}(\alpha(\sigma_e) \otimes \beta(\sigma_h) - \alpha(\sigma_h) \otimes \beta(\sigma_e))$$

Triplet

$$\left. \begin{array}{l} \alpha(\sigma_e) \otimes \alpha(\sigma_h) \\ \beta(\sigma_e) \otimes \beta(\sigma_h) \\ \frac{1}{\sqrt{2}}(\alpha(\sigma_e) \otimes \beta(\sigma_h) + \alpha(\sigma_h) \otimes \beta(\sigma_e)) \end{array} \right\}$$

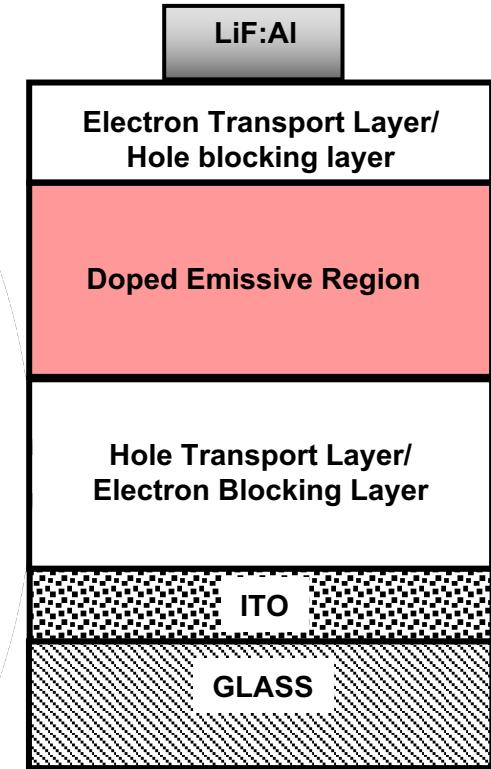
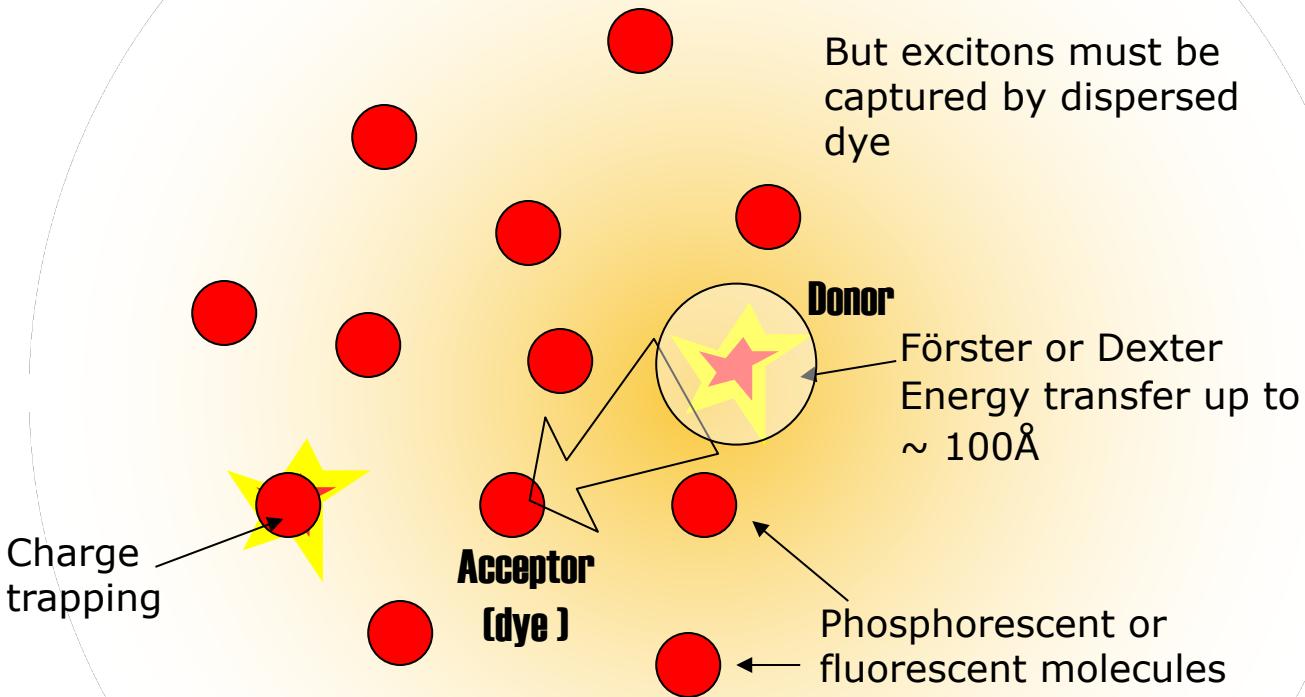


2. Only  $\sim 20\%$  of photons are coupled out of OLED devices due to TIR

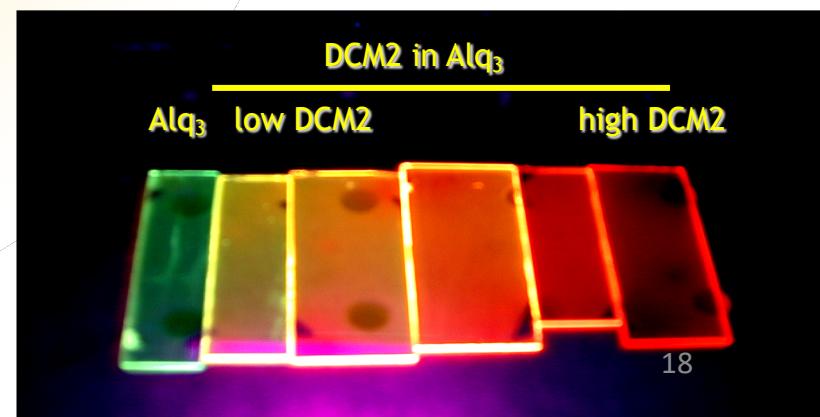
Maximum Fluorescence External Quantum Efficiency on Glass  $\sim 5\%$

Maximum Phosphorescence External Quantum Efficiency on Glass  $\sim 25\%$

# Efficiency Improves if Dopant Dispersed in Host

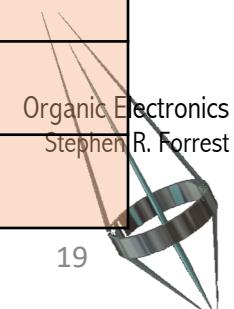


1. Charges trapped on dye molecules
2. Energy transferred from host
3. Effect used to increase color range and efficiency of OLEDs



# Lighting Comparisons

	<b>Incandescent</b>	<b>Fluorescent</b>	<b>LEDs</b>	<b>OLEDs</b>
<b>Efficacy</b>	17 lm/W	100 lm/W	80-90 lm/W – White 65 lm/W – warm white 240 lm/W-lab demo	150 lm/W Lab demos
<b>CRI</b>	100	80-85	80 – white 90 – warm white	Up to 95
<b>Form Factor</b>	Heat generating	Long or compact gas filled glass tube	Point source high intensity lamp	Large area thin diffuse source. Flexible, transparent
<b>Safety concerns</b>	Very hot	Contains mercury	Very hot in operation	None to date
<b>LT70 (K hours)</b>	1	20	50	30
<b>Dimmable</b>	Yes, but much lower efficacy	Yes, efficiency decreases	Yes, efficiency increases	Yes, efficiency increases
<b>Noise</b>	No	Yes	No	No
<b>Switching lifetime</b>	Poor	Poor	Excellent	Excellent
<b>Color Tunable</b>	No	No	Yes	Yes



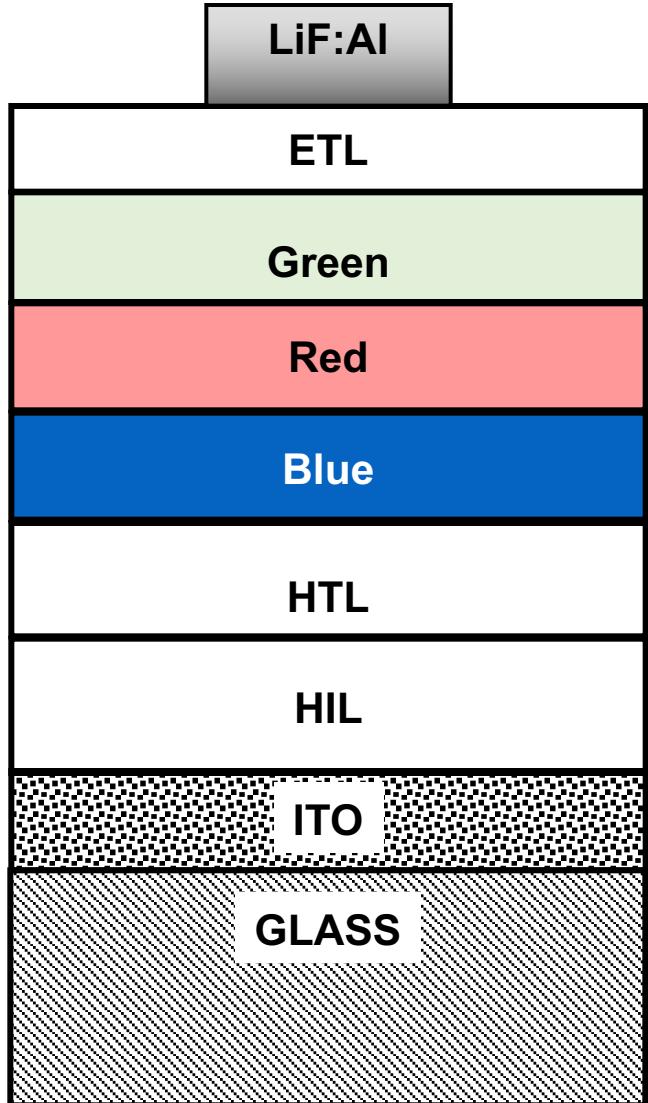
# OLEDs for White Light Generation

## Separating dopants into bands

- Prevents energy transfer between dopants.
- Control relative emission intensity of dopants by:
  - ✓ Varying doping concentrations
  - ✓ Adjusting the thickness of bands
  - ✓ Inserting blocking layers
  - ✓ Adjusting the position of the dopants relative to the HTL

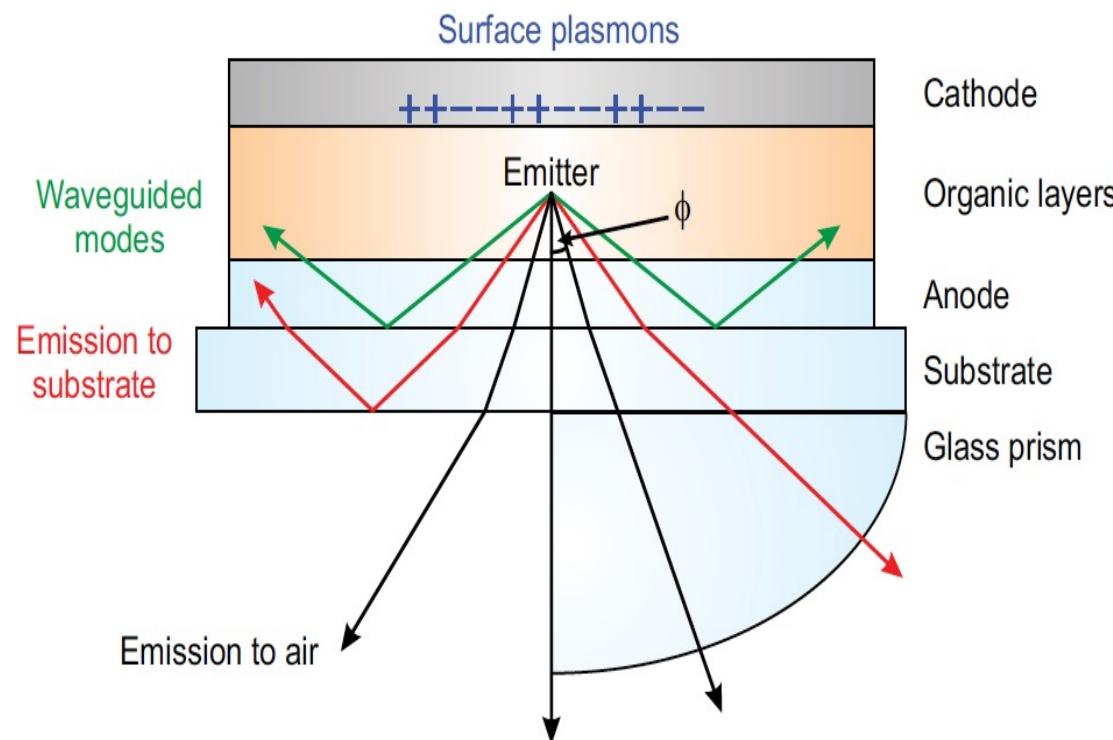
## Why does it work?

- Triplets can diffuse much further than singlets (measured ~1000Å)
- Good control over diffusion of excitons using blocking layers and layer thickness



# OLEDs: Not All Light Goes to the Viewer

- Optical paths outcoupled with hemispherical lens

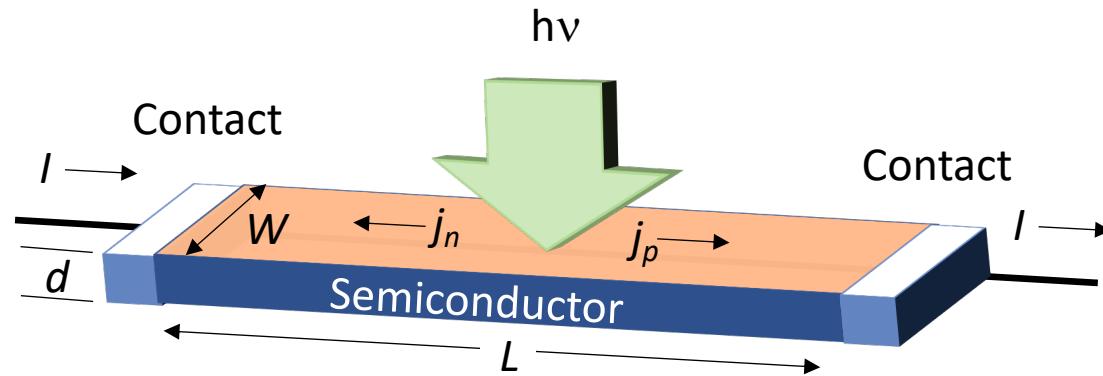


# Photodetectors

- Transducers that convert light to another energy form (in our case, electricity)
- Types
  - Photoconductors
  - Photodiodes
    - These are operated in the reverse-biased (photodetection) or photovoltaic mode
- Properties
  - Sensitivity & Efficiency
  - Spectral range
  - Bandwidth
  - Dynamic range

# Photoconductors

- Earliest organic electronic devices
- Simplest (no HJs needed)



When illuminated, conductivity changes

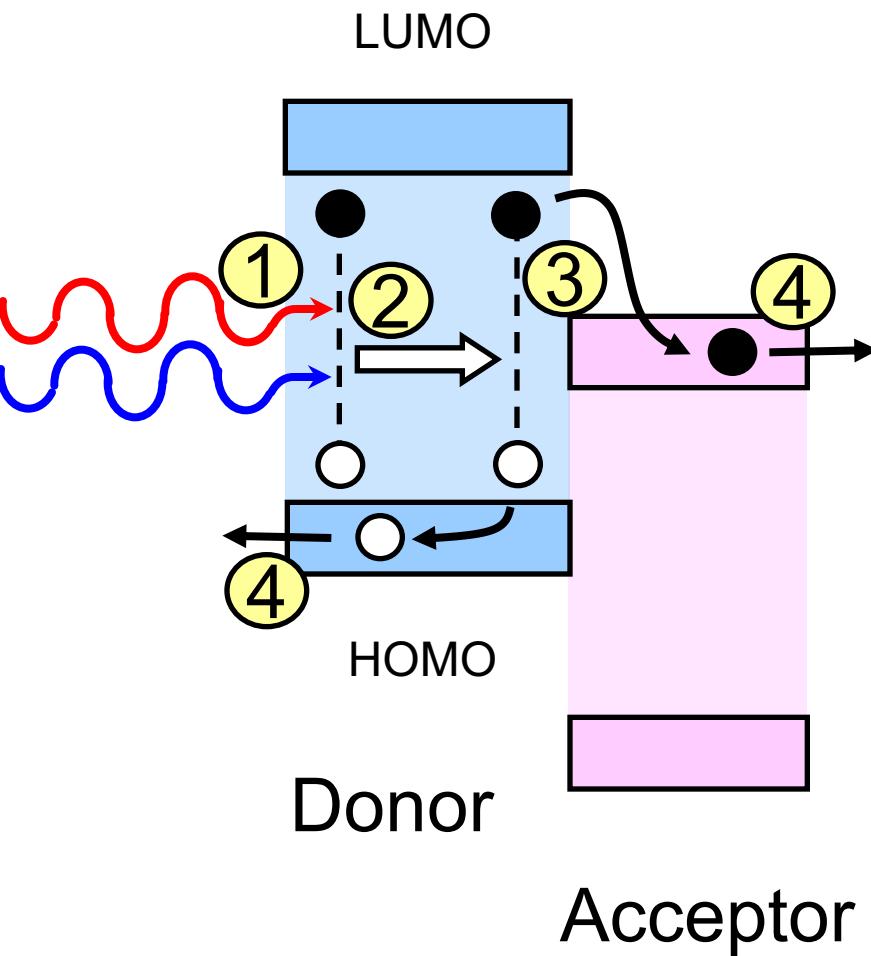
$$\sigma = q(\mu_n n + \mu_p p) \quad \left[ \begin{array}{l} p = p_{ph} + p_0 \\ n = n_{ph} + n_0 \end{array} \right] \quad n_{ph} = p_{ph}$$

Without background doping:  $n_0 = p_0 = n_i$

# Photoinduced Charge-Transfer at a Type II HJ

## The Basis of OPV Operation

Processes occurring at a Donor-Acceptor heterojunction

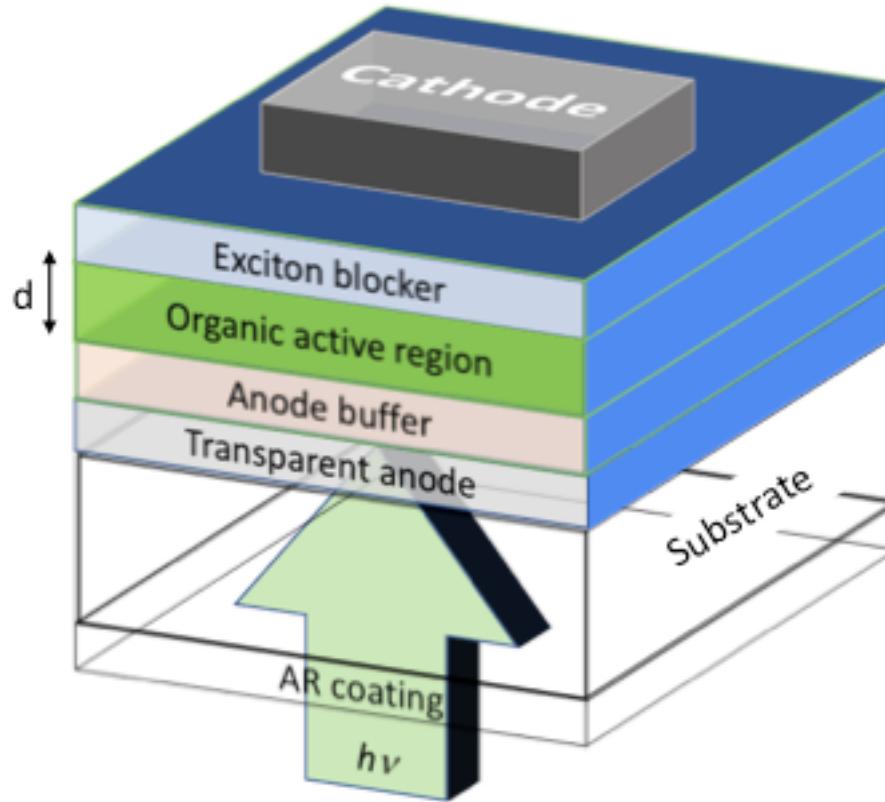


- ① Exciton generation by absorption of light ( $1/\alpha$ )
- ② Exciton diffusion over  $\sim L_D$
- ③ Exciton dissociation by rapid and efficient charge transfer
- ④ Charge extraction by the internal electric field

Typically:  $L_D \ll 1/\alpha$

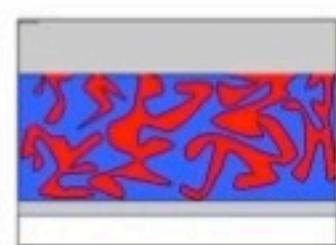
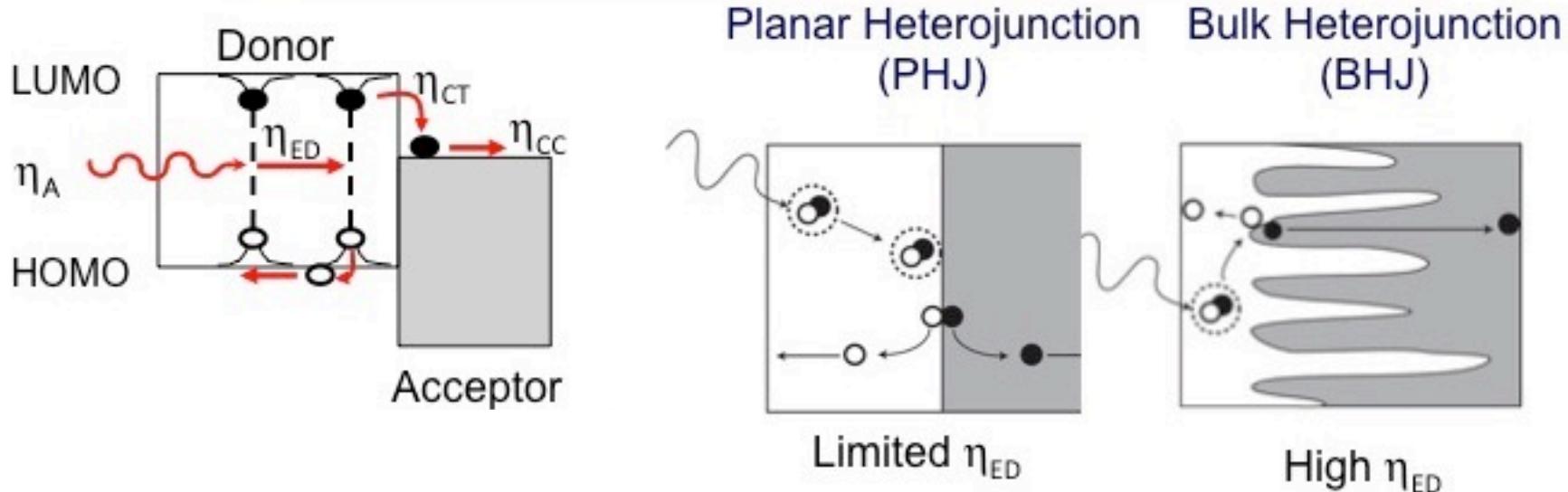
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# Basic OPD/OPV structure

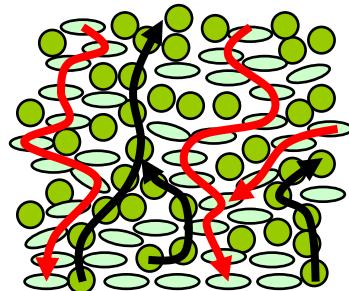


# Heterojunction Morphologies

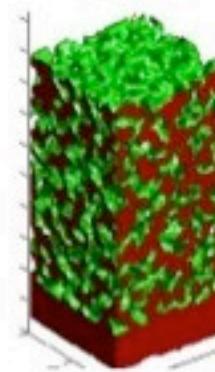
## Breaking the tradeoff between $L_D$ and $\alpha$ with BHJs



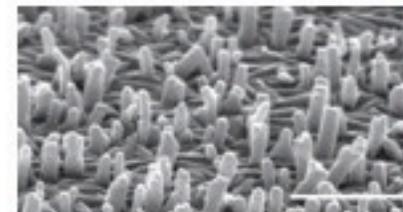
Bulk HJ



Mixed HJ



Annealed BHJ



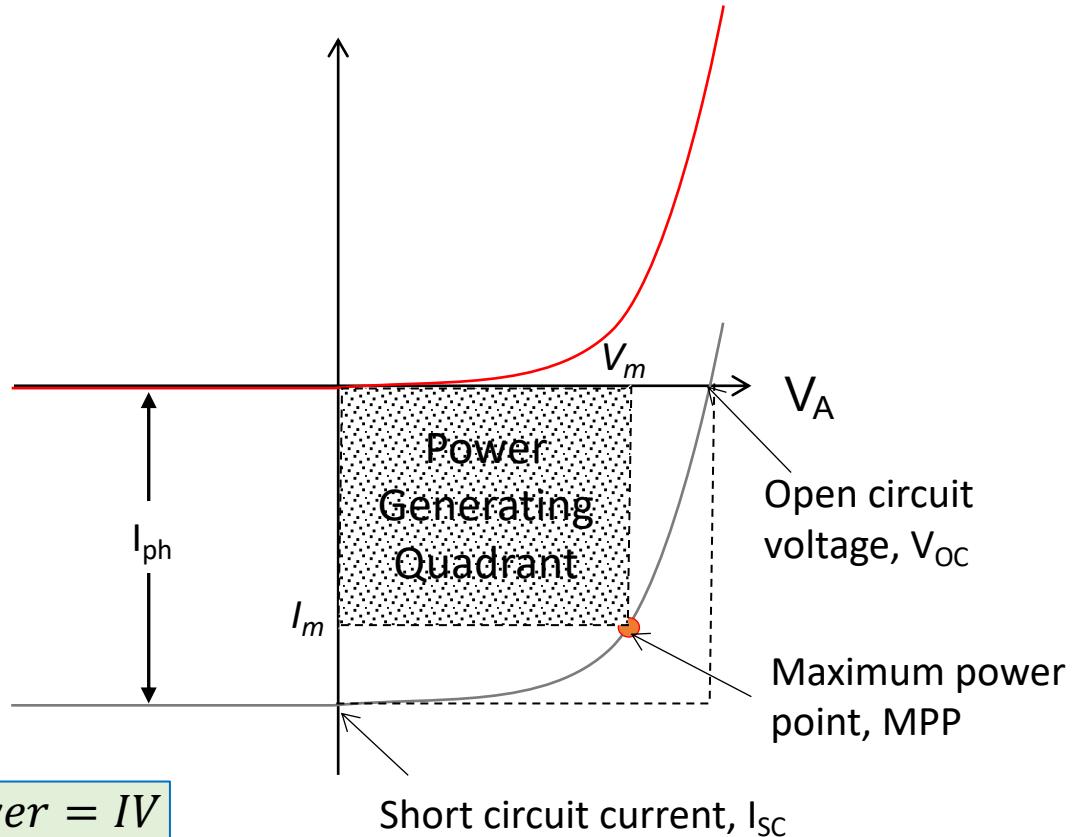
Controlled BHJ



# Solar Cell Basics

## Power Conversion Efficiency, $\eta_P$ :

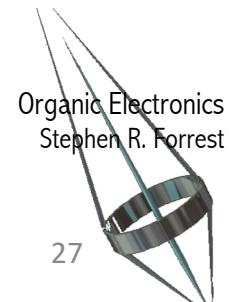
- $I_{SC} \propto$  number of photons absorbed
- $V_{OC}$  determined by material
- Fill factor (FF) related to device resistance



Maximum power generated:  $P_m = I_m V_m = FF I_{SC} V_{OC}$

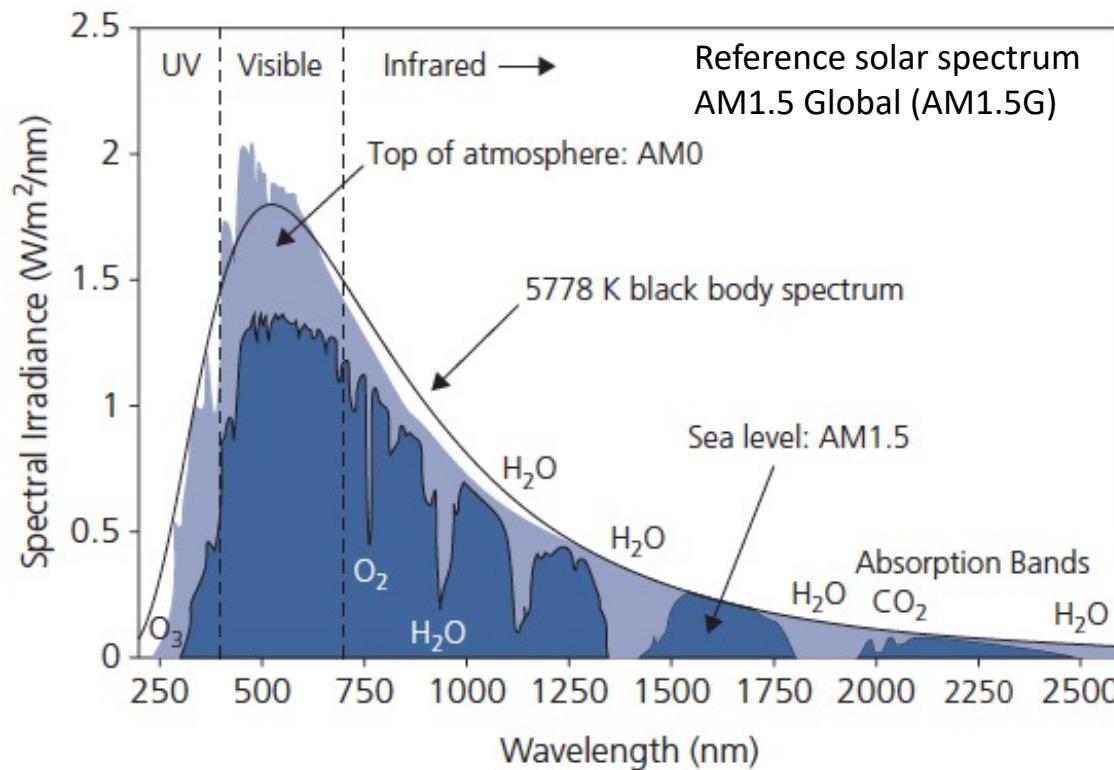
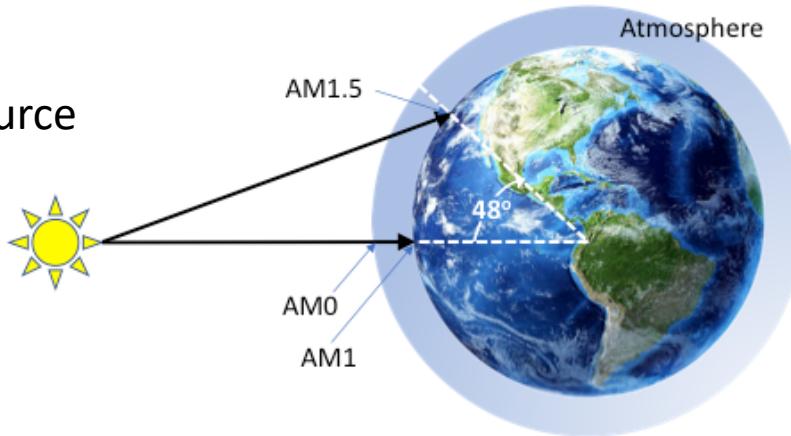
Fill Factor:  $FF = \frac{V_m I_m}{V_{OC} I_{SC}}$

$$\eta_P = \frac{FF \cdot I_{SC} \cdot V_{OC}}{P_{inc}}$$



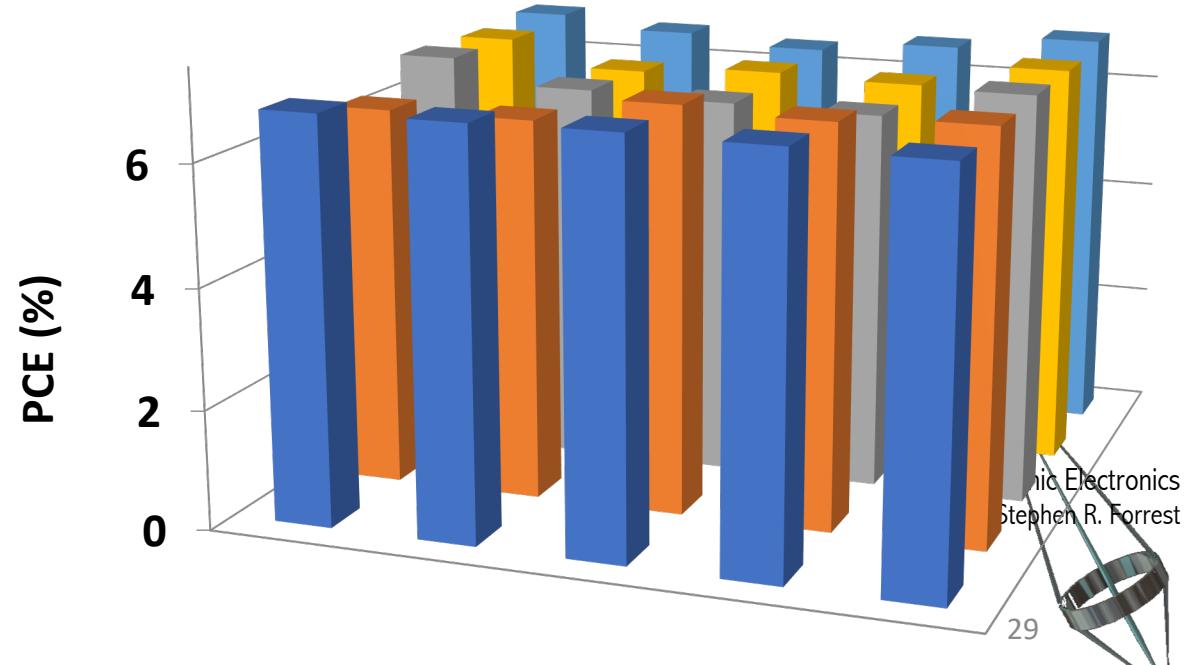
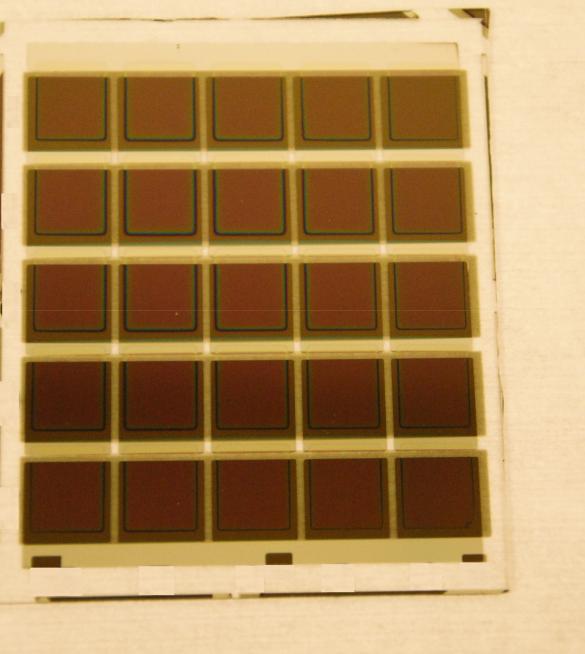
# Understanding Solar Cell Efficiency Limits

Consider the Source



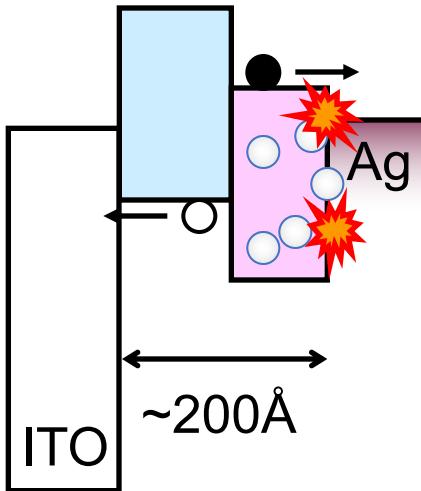
# Organic Solar Cell Challenges

- High efficiency (>17%)
  - Large Module Size
  - High Reliability (>20 years)
  - Low Production Cost (<\$0.50/Watt)



# Getting to High Efficiency: The Double Heterojunction

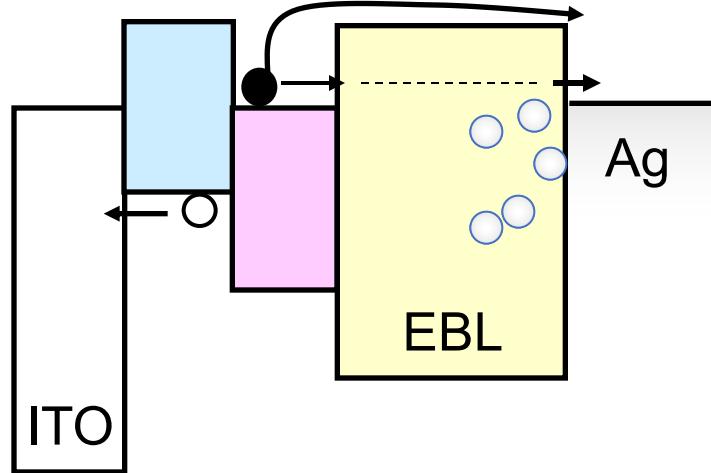
## Problem



(Tang cell: 1%)

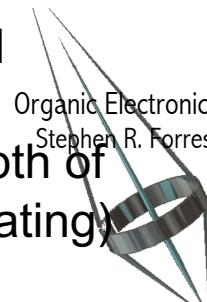
- cathode metal diffusion
- deposition damage
- exciton quenching
- vanishing optical field
- electrical shorts

## Solution



Introduce ‘Exciton Blocking Layer’ (EBL) to:

- confine excitons to active region
- separates active layer from metal
- act as a buffer to damage
- EBL thickness determined by depth of damage (if too thick, EBL is insulating)

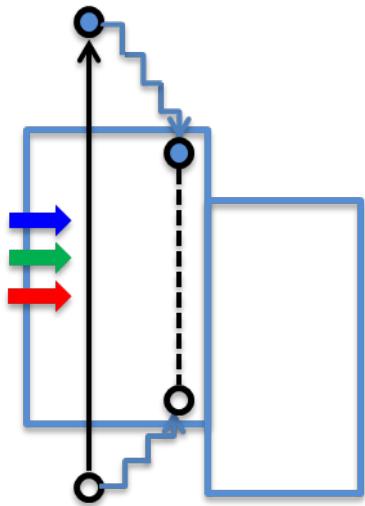


# Multijunction OPV cells: The Most Effective Way to Increase Efficiency

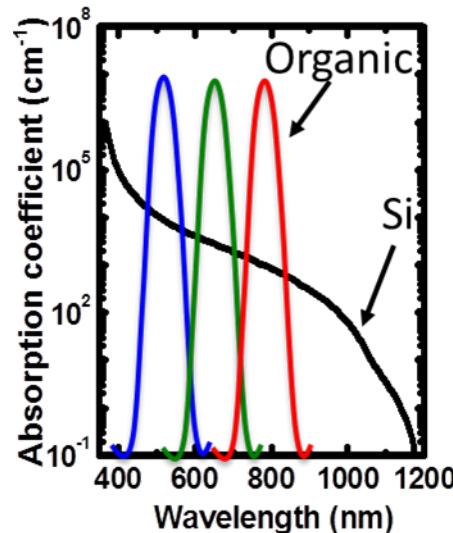
Can significantly exceed the thermodynamic limit of single junction cells

## Major issues of single junction OPV:

(a) Thermalization loss

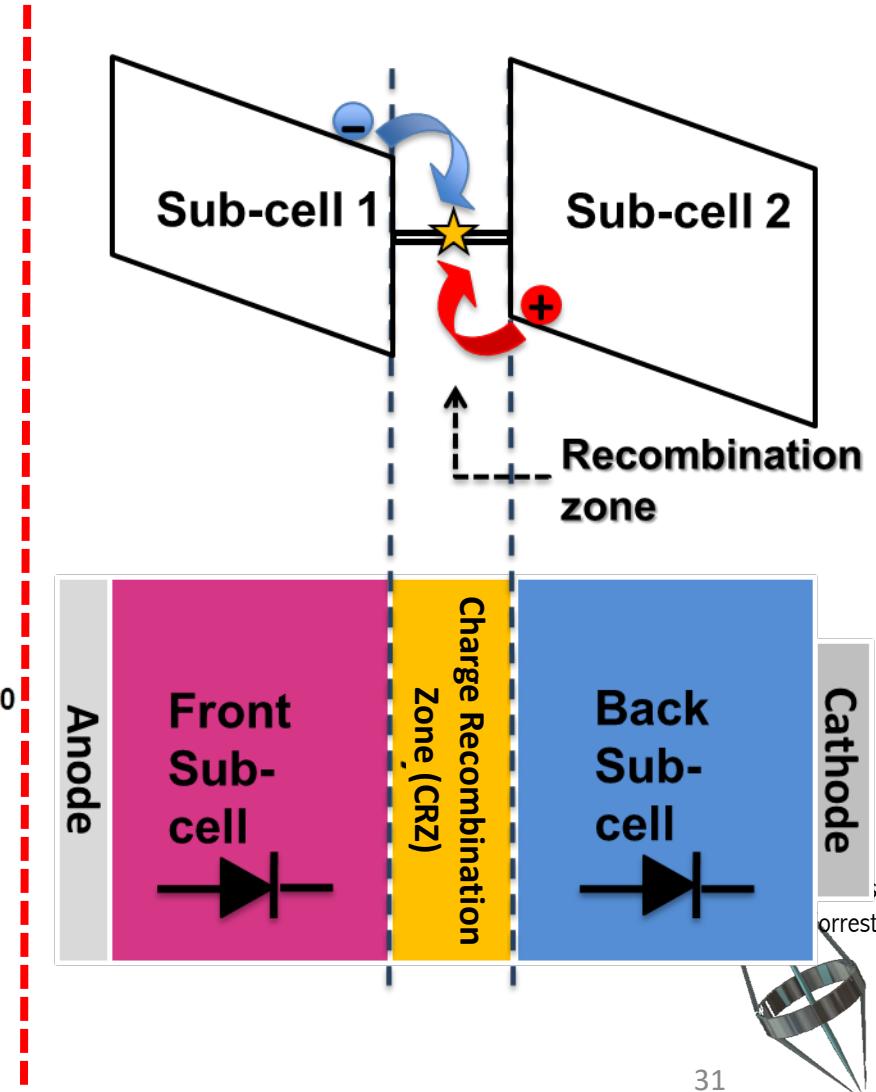


(b) Narrow absorption range

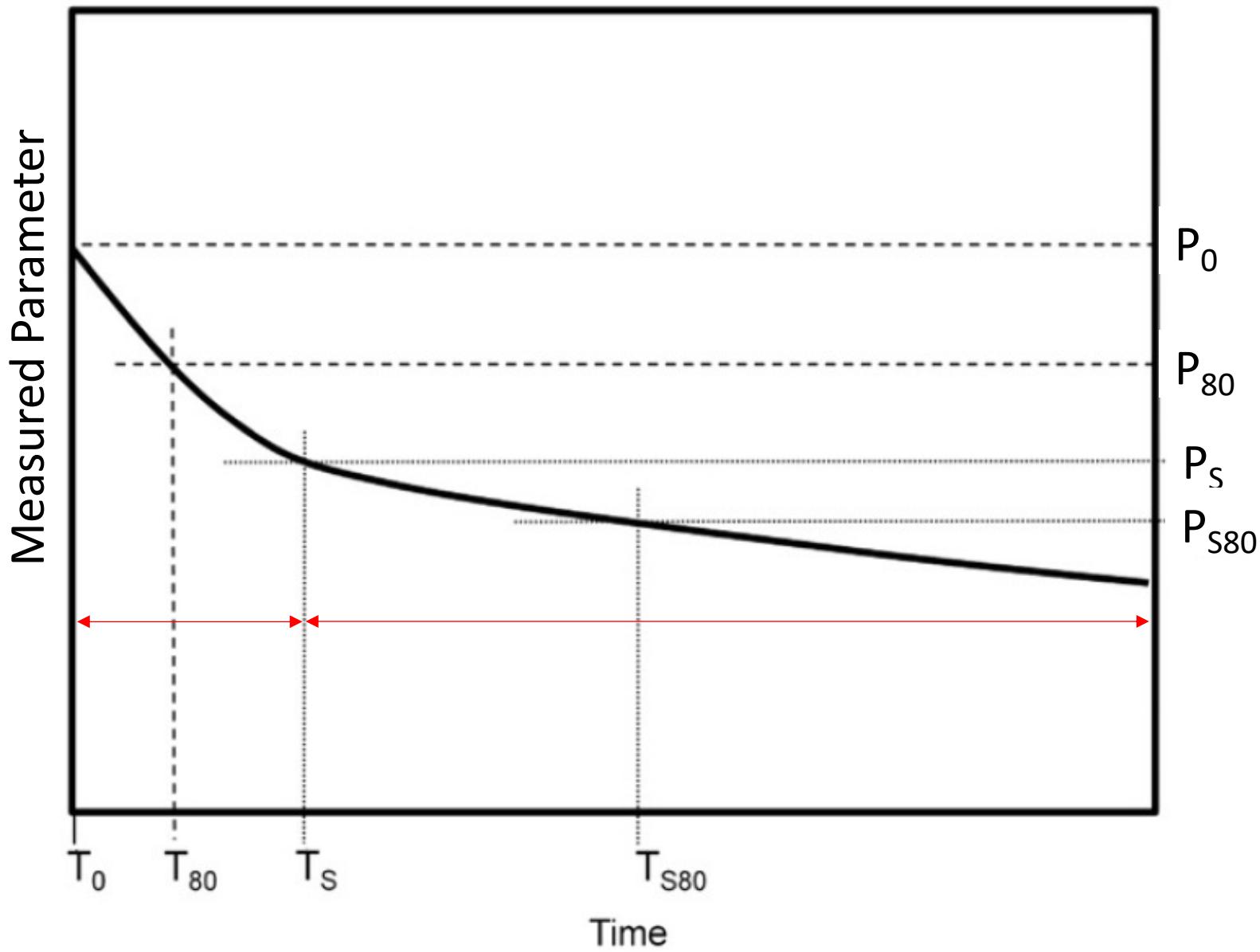


## Advantages of multijunction cells:

- Decrease thermalization losses
- Cover a broad spectral range

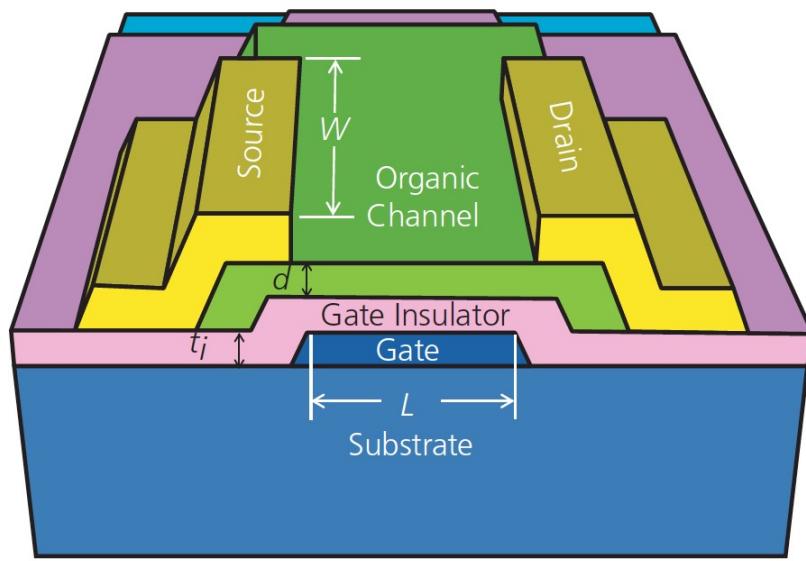


# Quantifying OPV Lifetimes

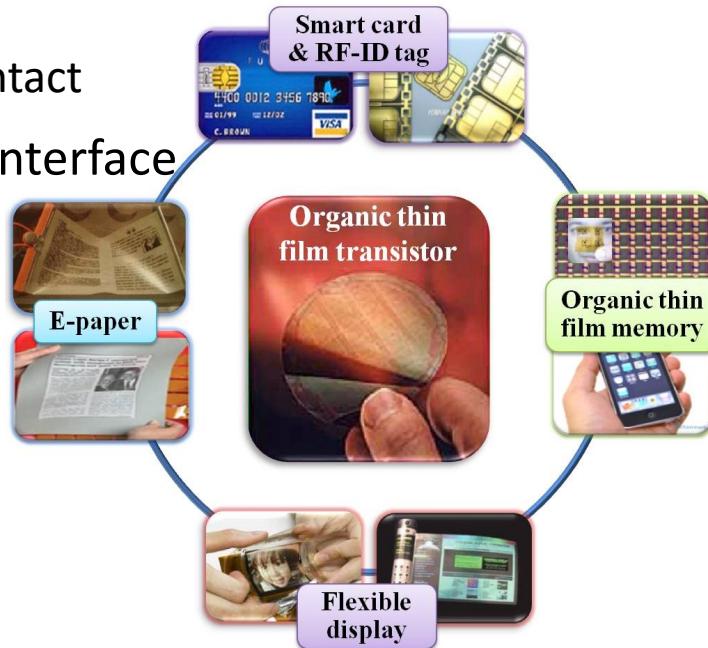


# What an OTFT looks like

- Several different configurations
  - Bottom gate, top gate, bottom SD contact, top SD contact
- Properties strongly influenced by dielectric/organic interface
- Configuration similar to inorganic TFTs
  - Metal oxide
  - a-Si
  - Etc.



Definitions of Contacts and Dimensions



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# OTFT applications must exploit advantages, and cannot be vulnerable to disadvantages

- PROs

- Flexible, conformable, ultralight
- Can be made over very large areas
- Suitable for large scale R2R manufacture

- CONS

- Cannot source large currents
- Characteristics drift over long periods in operation
- Limited bandwidth ( $\leq 1$  MHz in many cases)

# Organic Materials are Interesting for Electronics Because...

- They are *potentially* inexpensive
- Their properties can be "easily" modified through chemical synthesis
- They can be deposited on large area, flexible and/or conformable substrates
- They can be very lightweight
- They have excellent optical properties
- They can be manufactured "by the kilometer"

But remember.....

**If you are competing with silicon, go home. You've already lost!**

Organic Electronics  
Stephen R. Forrest

# What organic electronics are good for

- Low cost
- Large area
- Flexible
- Conformable/Stretchable
- Light weight
- Optoelectronics

# The Promise of Organics

## Making Large Area Electronics “By the Mile”

